Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H5N5005PL

Silicon N Channel MOS FET High Speed Power Switching

REJ03G0419-0400 Rev.4.00 May 13, 2009

Features

• Low on-resistance: $R_{DS(on)} = 0.070 \Omega$ typ.

• Low leakage current: $I_{DSS} = 10 \mu A \text{ max (at } V_{DS} = 500 \text{ V)}$

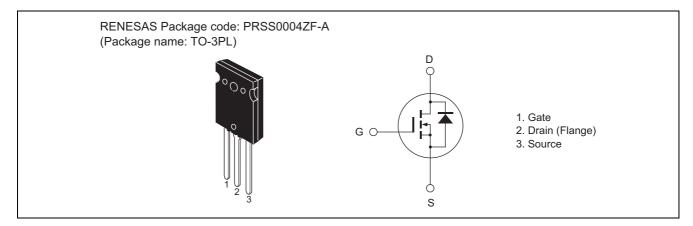
• High speed switching: t_f = 300 ns typ (at V_{GS} = 10 V, I_D = 30 A, R_L = 8.33 Ω)

• Low gate charge: Qg = 300 nC typ (at $V_{DD} = 400 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 60 \text{ A}$)

• Avalanche ratings

• Built-in fast recovery diode: $t_{rr} = 220$ ns typ

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	500	V
Gate to Source voltage	V_{GSS}	±30	V
Drain current	I _D	60	Α
Drain peak current	I _{D (pulse)} Note1	240	A
Body-Drain diode reverse Drain current	I _{DR}	60	Α
Body-Drain diode reverse Drain peak current	I _{DR (pulse)} Note1	240	Α
Avalanche current	I _{AP} Note3	30	Α
Channel dissipation	Pch Note2	270	W
Channel to case thermal impedance	θch-c	0.463	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. STch = 25° C, Tch $\leq 150^{\circ}$ C

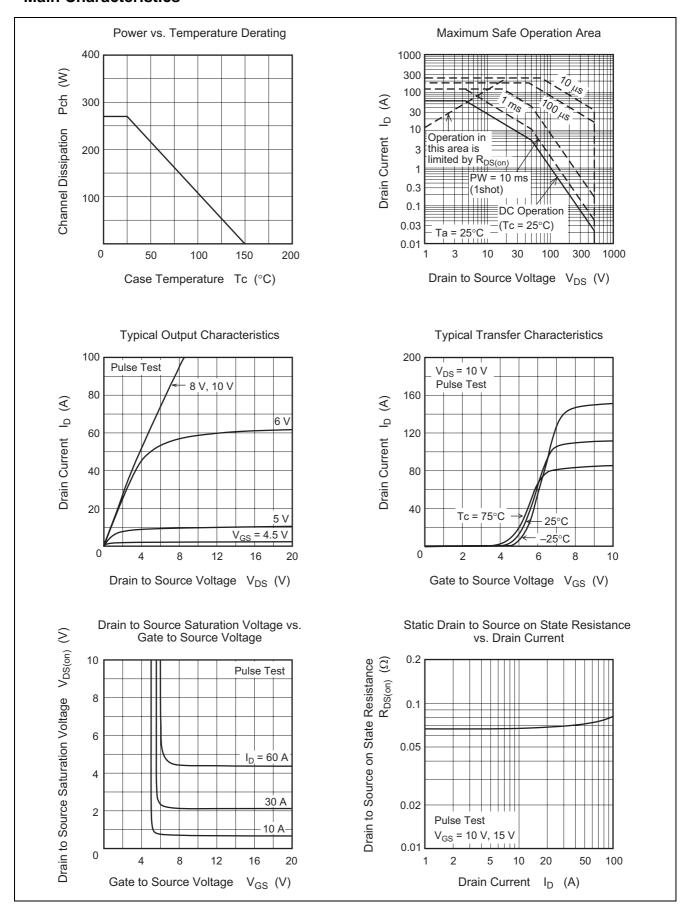
Electrical Characteristics

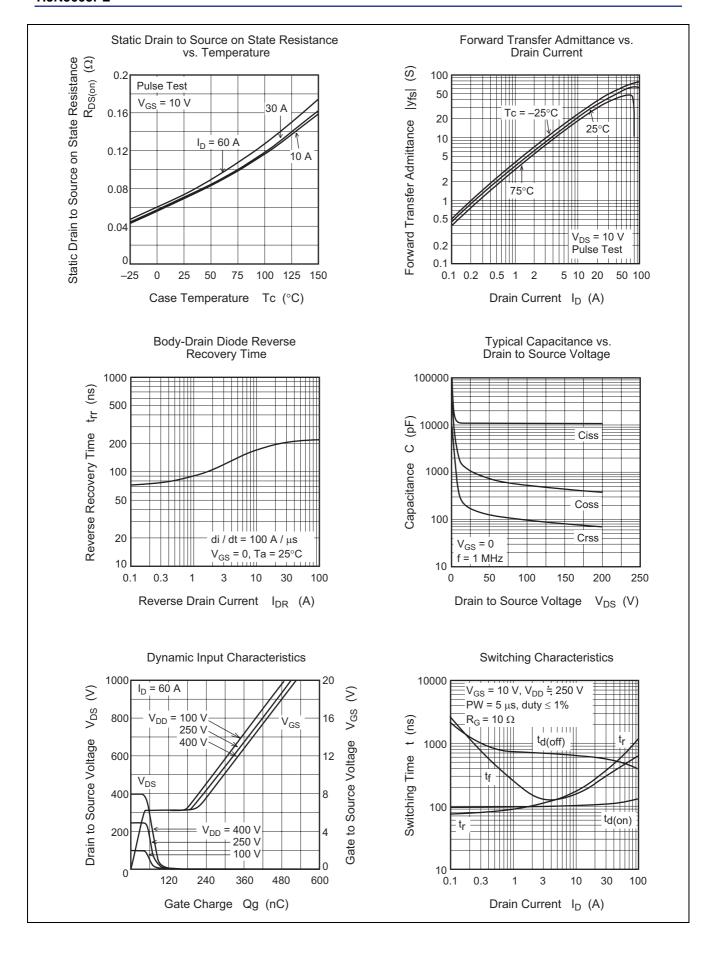
 $(Ta = 25^{\circ}C)$

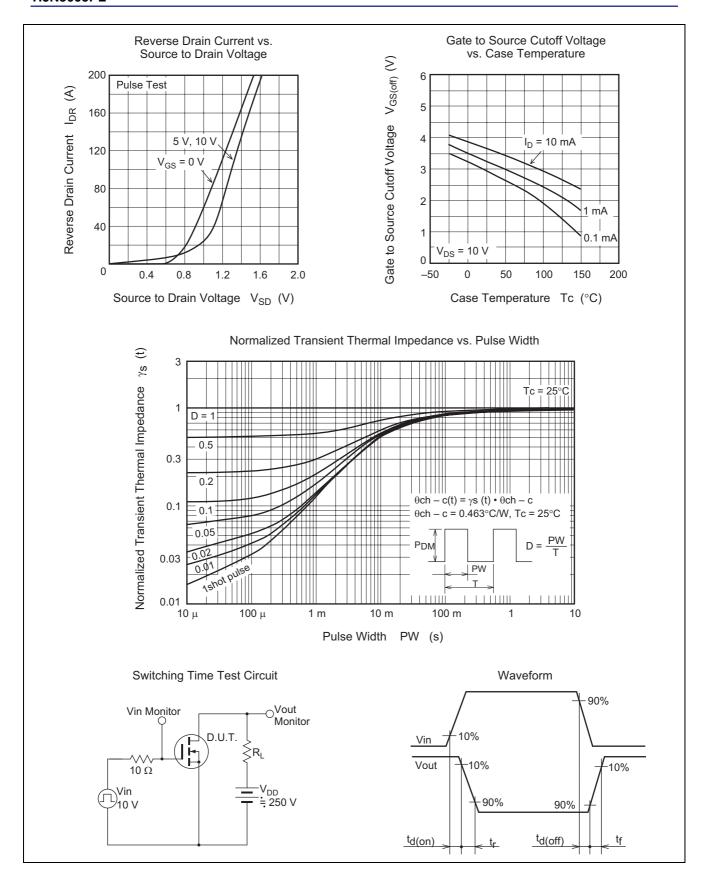
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero Gate voltage Drain current	I _{DSS}		_	10	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to Source leak current	I _{GSS}	1	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to Source cutoff voltage	V _{GS(off)}	2.0	_	4.0	V	V_{DS} = 10 V, I_{D} = 1 mA
Forward transfer admittance	y _{fs}	25	42	_	S	$I_D = 30 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Static Drain to Source on state resistance	R _{DS(on)}	_	0.070	0.085	Ω	I _D = 30 A, V _{GS} = 10 V ^{Note4}
Input capacitance	Ciss	1	10550	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	1060	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	180	_	pF	f = 1 MHz
Turn-on delay time	$t_{d(on)}$	_	115	_	ns	I _D = 30 A
Rise time	t _r	_	380	_	ns	V _{GS} = 10 V
Turn-off delay time	$t_{\text{d(off)}}$	_	560	_	ns	R_L = 8.33 $Ω$ Rg = 10 $Ω$
Fall time	t _f	_	300	_	ns	
Total Gate charge	Qg	_	300	_	nC	V _{DD} = 400 V
Gate to Source charge	Qgs		40	_	nC	V _{GS} = 10 V
Gate to Drain charge	Qgd	_	155	_	nC	I _D = 60 A
Body-Drain diode forward voltage	V_{DF}	_	1.0	1.5	V	$I_F = 60 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-Drain diode reverse recovery time	t _{rr}	_	220	_	ns	$I_F = 60 \text{ A}, V_{GS} = 0$ $di_F/dt = 100A/\mu s$
Body-Drain diode reverse recovery charge	Q _{rr}	_	2.0	_	μС	

Note: 4. Pulse test

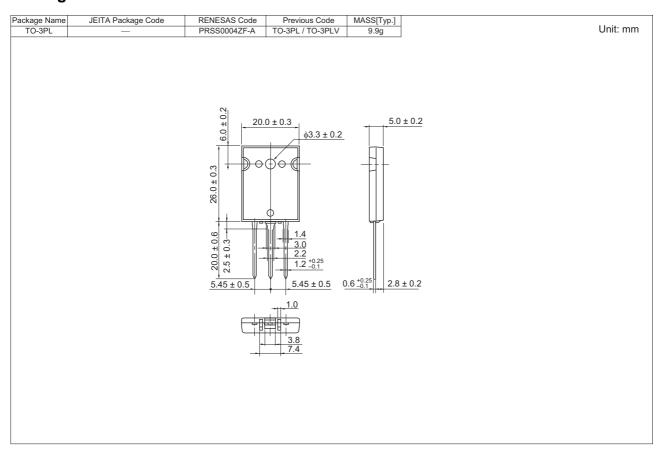
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
H5N5005PL-E	250 pcs	Box (Tube)

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